

## N-Channel High Density Trench MOSFET

### Features:

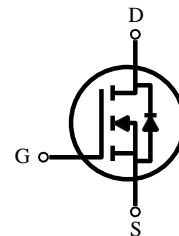
- Super high dense cell trench design for low  $R_{DS(on)}$ .
- Rugged and reliable.
- Surface Mount package.

SOT-23



### PRODUCT SUMMARY

$V_{DSS}$	$I_D$	$R_{DS(on)}$ (m-ohm) Max
20V	5.8	25 @ $V_{GS} = 4.5V$
	4.6	39 @ $V_{GS} = 2.5V$



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Drain Current-Continuous <sup>a</sup> @ $T_A = 25^\circ C$ -Pulse <sup>b</sup>	$I_D$	5.8	A
	$I_{DM}$	24	A
Drain-Source Diode Forward Current <sup>a</sup>	$I_S$	1.7	A
Maximum Power Dissipation <sup>a</sup>	$P_D$	1.25	W
		0.75	
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	- 55 to 150	$^\circ C$

### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient <sup>a</sup>	$R_{thJA}$	100	$^\circ C/W$
--	------------	-----	--------------

Note

a. Surface Mounted on FR4 Board ,  $t \leq 10sec$ .

b. Pulse width limited by maximum junction temperature.



**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ <sup>c</sup>	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V , I <sub>D</sub> = 250uA	20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 20V , V <sub>GS</sub> = 0V			1	uA
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>GS</sub> = 12V , V <sub>DS</sub> = 0V			100	nA
<b>ON CHARACTERISTICS</b> <sup>b</sup>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250uA	0.6	0.83	1.5	V
Drain-Source On-State Resistance	R <sub>DSS(on)</sub>	V <sub>GS</sub> = 4.5V , I <sub>D</sub> = 5.8A		21	25	m-ohm
		V <sub>GS</sub> = 2.5V , I <sub>D</sub> = 4.6A		32	39	
<b>DRAIN-SOURCE DIODE CHARACTERISTICS</b> <sup>b</sup>						
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0V , I <sub>S</sub> = 1.7A			1.2	V
<b>DYNAMIC CHARACTERISTICS</b> <sup>c</sup>						
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> = 8V , V <sub>GS</sub> = 0V f = 1.0MHz		512		pF
Output Capacitance	C <sub>OSS</sub>			130		pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			105		pF
<b>SWITCHING CHARACTERISTICS</b> <sup>c</sup>						
Turn-On Delay Time	t <sub>D(ON)</sub>	V <sub>DD</sub> = 10V , I <sub>D</sub> = 3A V <sub>GEN</sub> = 4.5V R <sub>L</sub> = 3.3 ohm R <sub>GEN</sub> = 6 ohm		9.8		ns
Rise Time	t <sub>r</sub>			3.8		ns
Turn-Off Delay Time	t <sub>D(OFF)</sub>			21		ns
Fall Time	t <sub>f</sub>			5.2		ns
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> = 10V , I <sub>D</sub> = 3A V <sub>GS</sub> = 4.5V		5.7		nC
Gate-Source Charge	Q <sub>gs</sub>			1.6		nC
Gate-Drain Charge	Q <sub>gd</sub>			1.3		nC

Note

b. Pulse Test Pulse width ≤ 300us , Duty Cycle ≤ 2% .

c. Guaranteed by design , not subject to production testing.

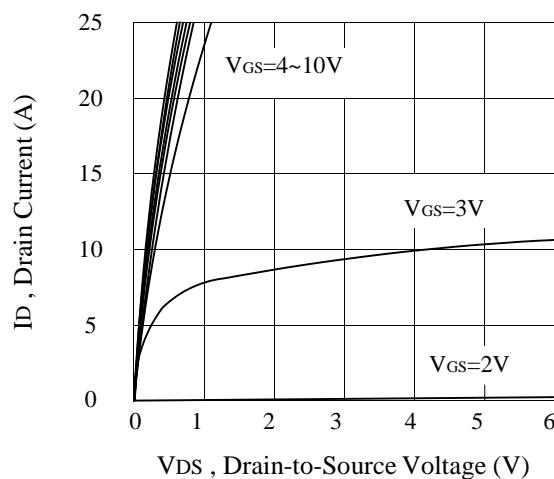


Figure 1. Output Characteristics

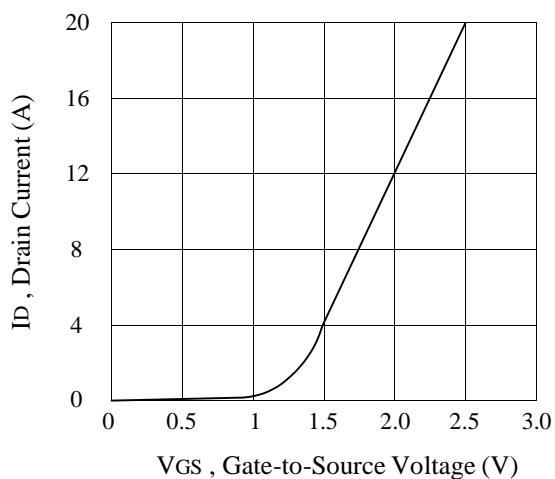


Figure 2. Transfer Characteristics

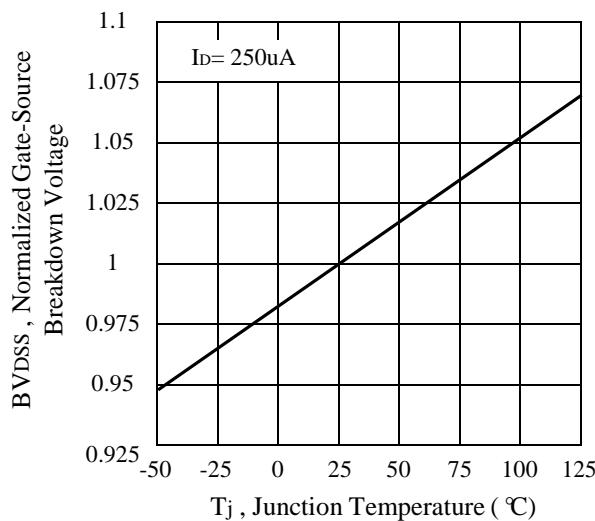


Figure 3. Breakdown Voltage Variation with Temperature

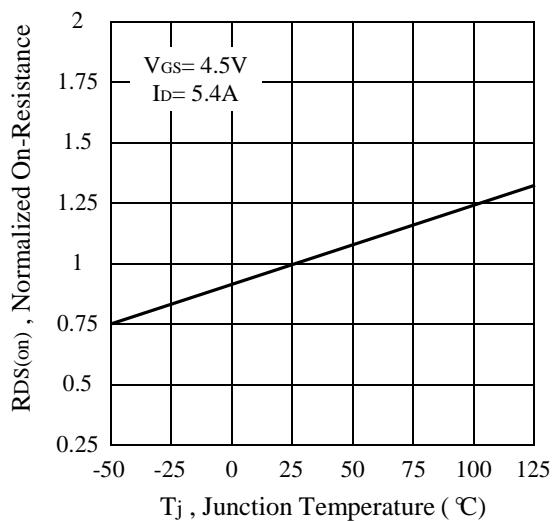


Figure 4. On-Resistance Variation with Temperature

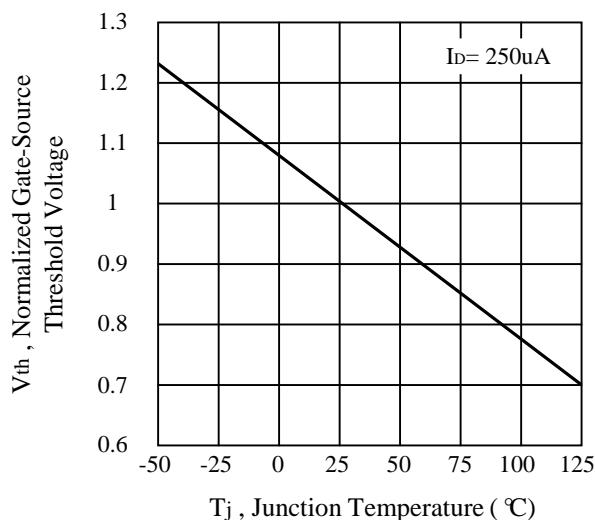


Figure 5. Gate Threshold Variation with Temperature

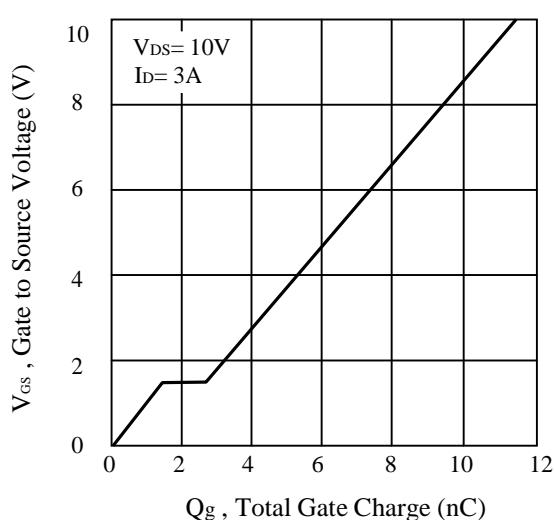
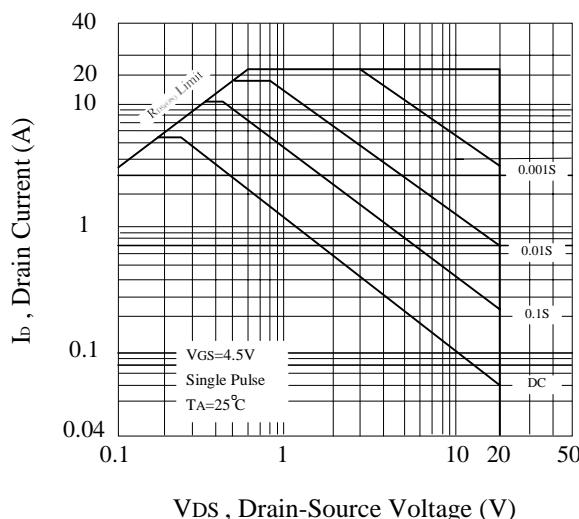
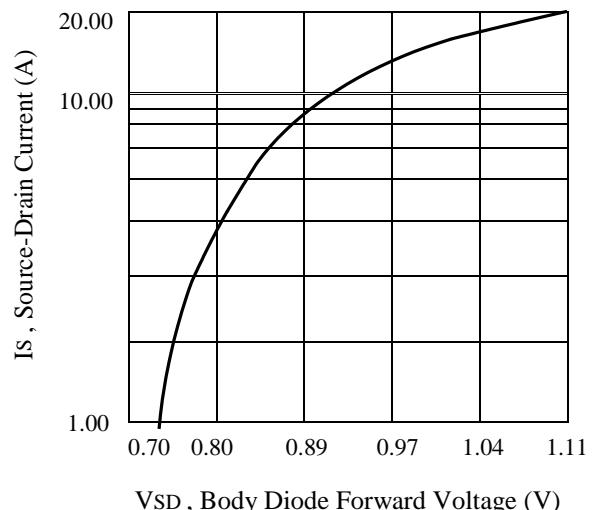


Figure 6. Gate Charge

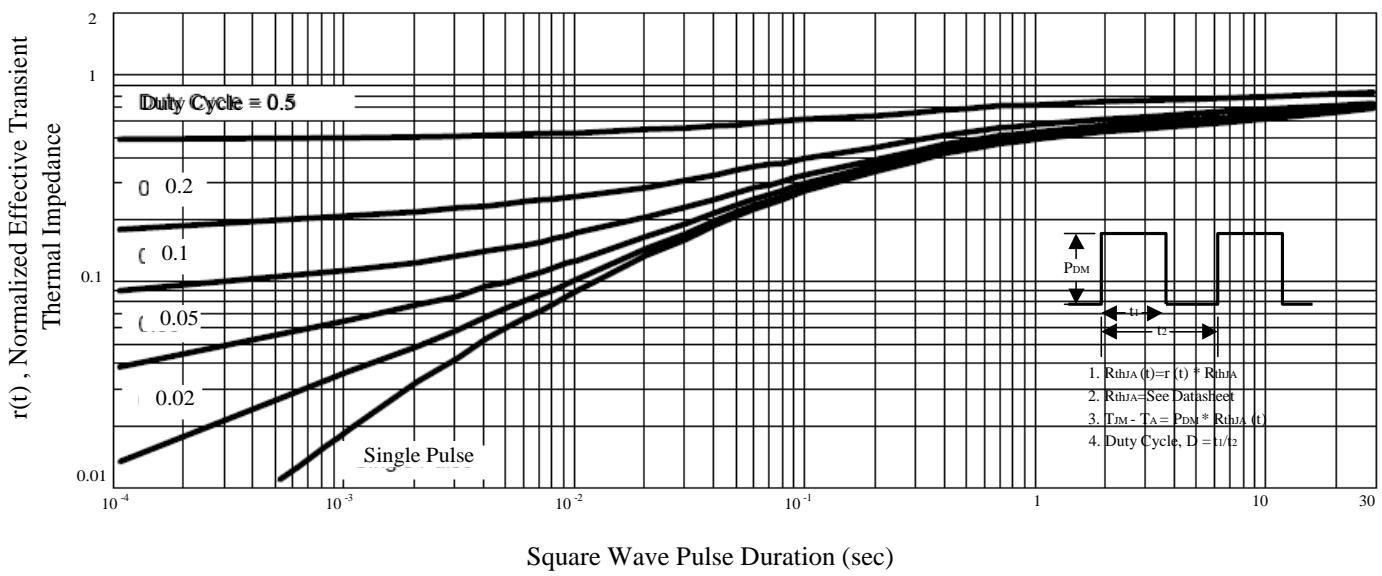
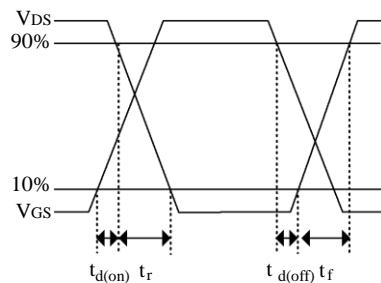
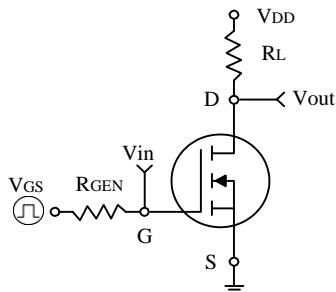


V<sub>DS</sub>, Drain-Source Voltage (V)

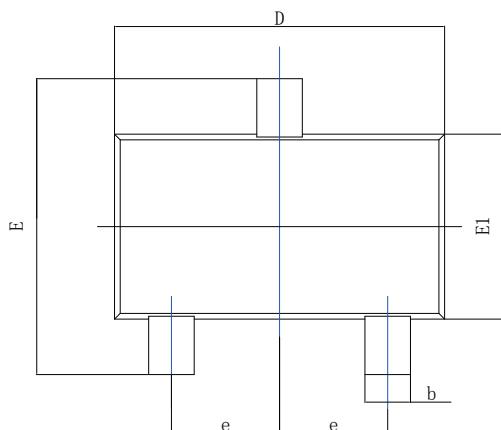
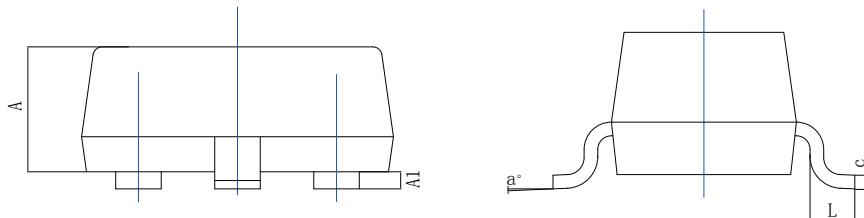
Figure 7. Maximum Safe Operating Area



V<sub>SD</sub>, Body Diode Forward Voltage (V)

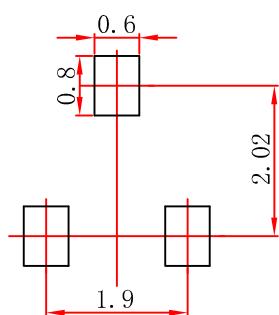


## SOT-23 Dimension



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	--	--	1.35
A1	0.04	0.07	0.15
b	0.30	0.40	0.50
c	0.08	--	0.21
D	2.72	2.92	3.12
E	2.10	2.33	2.64
E1	1.10	1.30	1.50
e	0.95BSC		
L	0.20	--	0.60
a °	0 °	--	8 °

## SOT-23 Suggested Pad Layout

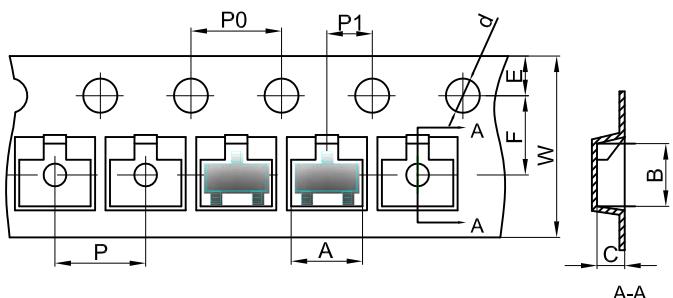


### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

## SOT-23 Tape and Reel

### SOT-23 Embossed Carrier Tape

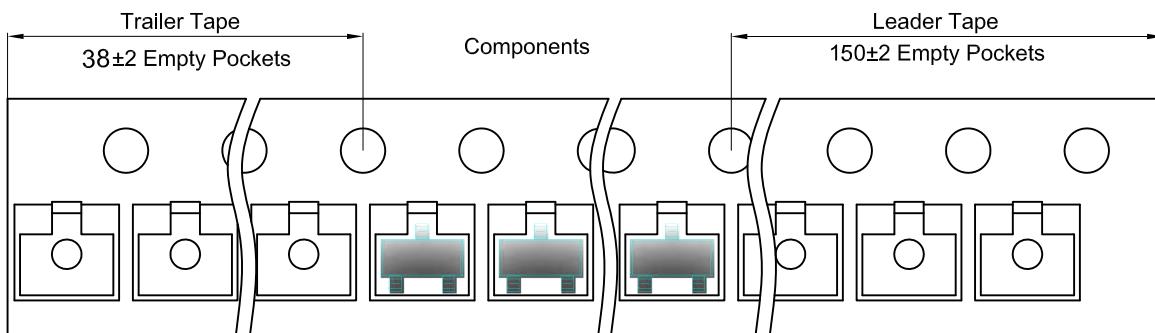


#### Packaging Description:

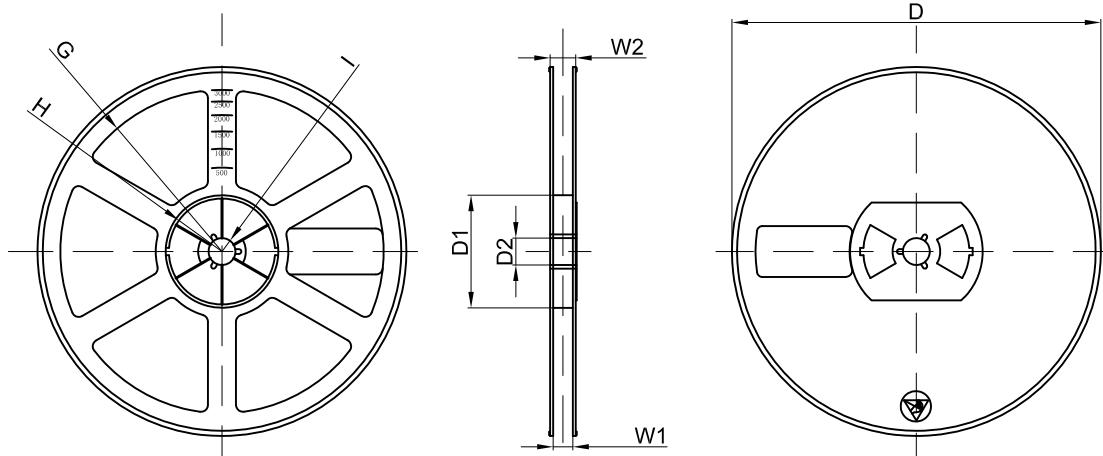
SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.55	1.75	3.50	4.00	4.00	2.00	8.00

### SOT-23 Tape Leader and Trailer



### SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	24,000 pcs	190×180×105	120,000 pcs	544×200×199	